



Specification				Min.	Typ.	Max.
Supply voltage	V _{cc}	±47V	Neutral voltage	V _n	-70mV	70mV
Max. Supply voltage	V _{CCmax}	±69V	Quiescent Current	I _{cco}	n/a mA	n/a mA
Input impedance	R _i	55kohm	Max. Coll. Current	I _{cc}		80mA
Thermal resistance	θ _{j-c}	1.7 °C/W	Total harmonic dist.	THD		0.2%
Junction temperature	T _j	150 °C	Output Power	P _o	2x125W	
Operating IC substrate temp.	T _c	125 °C	Outp. Noise Voltage	V _{no}		1.0mVrms
Storage temperature	T _{stg}	-30...+125 °C				

